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EFC6602R

N-Channel Power MOSFET 12V, 18A, 5.9mΩ, Dual EFCP

Features

- 2.5V drive
- Common-drain type
- 2KV ESD HBM
- Protection diode in
- Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C

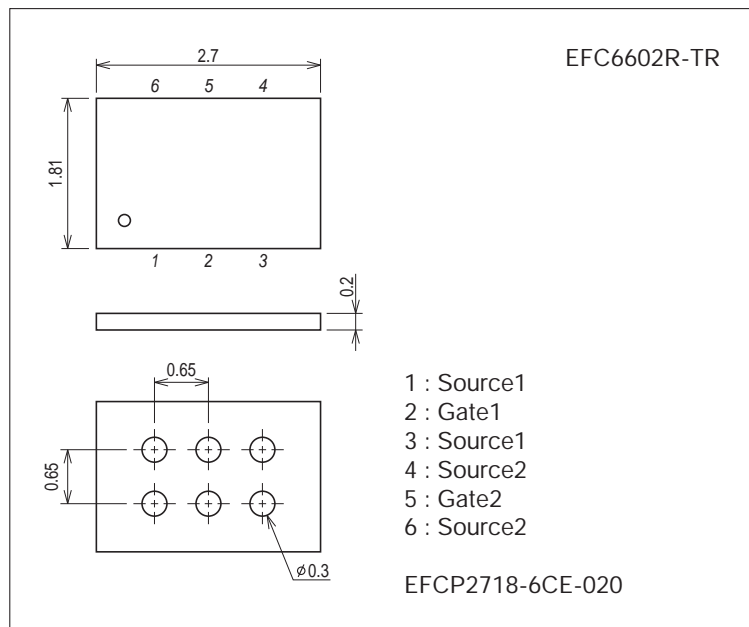
Parameter	Symbol	Conditions	Ratings	Unit
Source-to-Source Voltage	V _{SSS}		12	V
Gate-to-Source Voltage	V _{GSS}		±12	V
Source Current (DC)	I _S		18	A
Source Current (Pulse)	I _{SP}	PW≤10μs, duty cycle≤1%	60	A
Total Dissipation	P _T	When mounted on ceramic substrate (5000mm²×0.8mm)	2.0	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

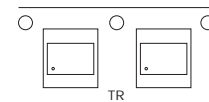
7073-001



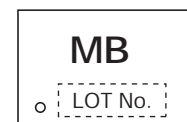
Product & Package Information

- Package : EFCP
- JEITA, JEDEC : -
- Minimum Packing Quantity : 5,000 pcs./reel

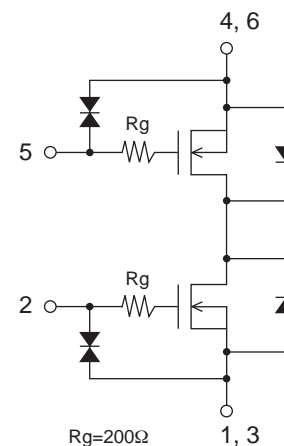
Taping Type : TR



Marking



Electrical Connection



EFC6602R

Electrical Characteristics at Ta=25°C

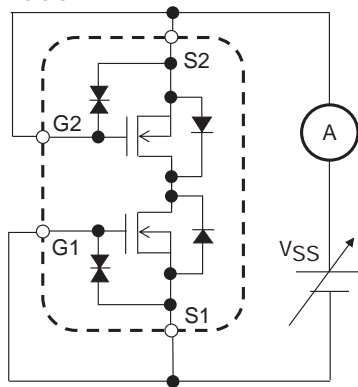
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Source-to-Source Breakdown Voltage	$V_{(BR)SSS}$	$I_S=1mA$, $V_{GS}=0V$ Test Circuit 1	12			V
Zero-Gate Voltage Source Current	I_{SSS}	$V_{SS}=10V$, $V_{GS}=0V$ Test Circuit 1			1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V$, $V_{SS}=0V$ Test Circuit 2			± 1	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{SS}=6V$, $I_S=1mA$ Test Circuit 3	0.5		1.3	V
Forward Transfer Admittance	$ y_{fs} $	$V_{SS}=6V$, $I_S=3A$ Test Circuit 4		13		S
Static Source-to-Source On-State Resistance	$R_{SS(on)1}$	$I_S=3A$, $V_{GS}=4.5V$ Test Circuit 5	3.1	4.5	5.9	$m\Omega$
	$R_{SS(on)2}$	$I_S=3A$, $V_{GS}=4.0V$ Test Circuit 5	3.3	4.8	6.3	$m\Omega$
	$R_{SS(on)3}$	$I_S=3A$, $V_{GS}=3.8V$ Test Circuit 5	3.5	5	6.5	$m\Omega$
	$R_{SS(on)4}$	$I_S=3A$, $V_{GS}=3.1V$ Test Circuit 5	4.0	5.8	8.2	$m\Omega$
	$R_{SS(on)5}$	$I_S=3A$, $V_{GS}=2.5V$ Test Circuit 5	5.2	7.5	11	$m\Omega$
Turn-ON Delay Time	$t_{d(on)}$	$V_{DD}=6V$, $V_{GS}=4.5V$, $I_S=3A$ Test Circuit 7		530		ns
Rise Time	t_r			2100		ns
Turn-OFF Delay Time	$t_{d(off)}$			6200		ns
Fall Time	t_f			5500		ns
Total Gate Charge	Q_g	$V_{DD}=6V$, $V_{GS}=4.5V$, $I_S=18A$ Test Circuit 8		55		nC
Forward Source-to-Source Voltage	$V_{F(S-S)}$	$I_S=3A$, $V_{GS}=0V$ Test Circuit 6		0.76	1.2	V

Ordering Information

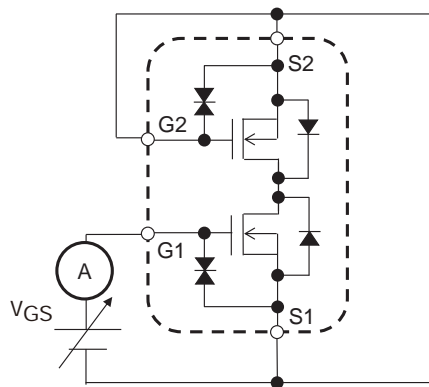
Device	Package	Shipping	memo
EFC6602R-TR	EFCP	5,000pcs./reel	Pb Free and Halogen Free

Test circuits are example of measuring FET1 side

Test Circuit 1
 I_{SSS}

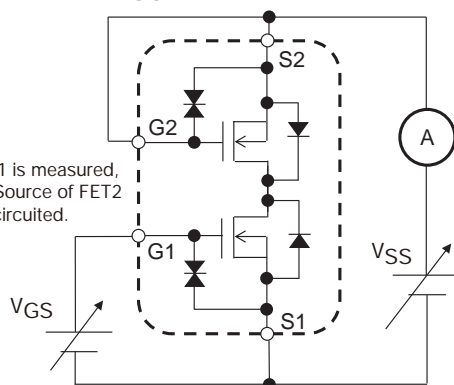


Test Circuit 2
 I_{GSS}



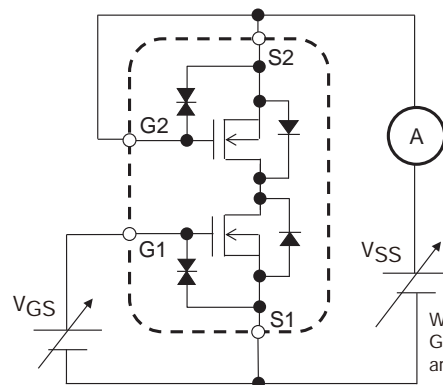
When FET1 is measured, Gate and Source of FET2 are short-circuited.

Test Circuit 3
 $V_{GS(off)}$



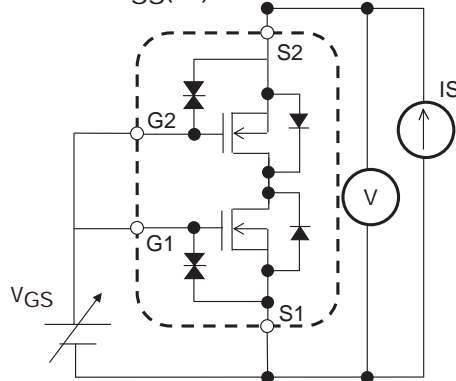
When FET1 is measured, Gate and Source of FET2 are short-circuited.

Test Circuit 4
 $|y_{fs}|$

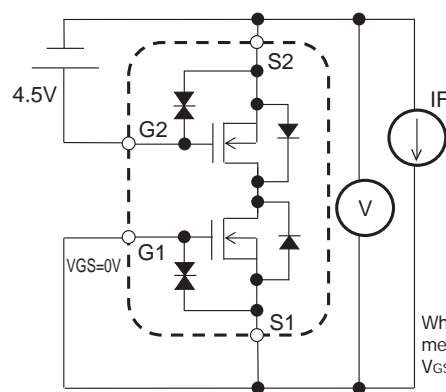


When FET1 is measured, Gate and Source of FET2 are short-circuited.

Test Circuit 5
 $R_{SS(on)}$

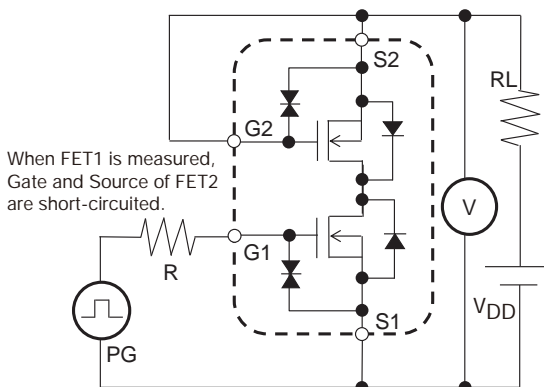


Test Circuit 6
 $V_F(S-S)$



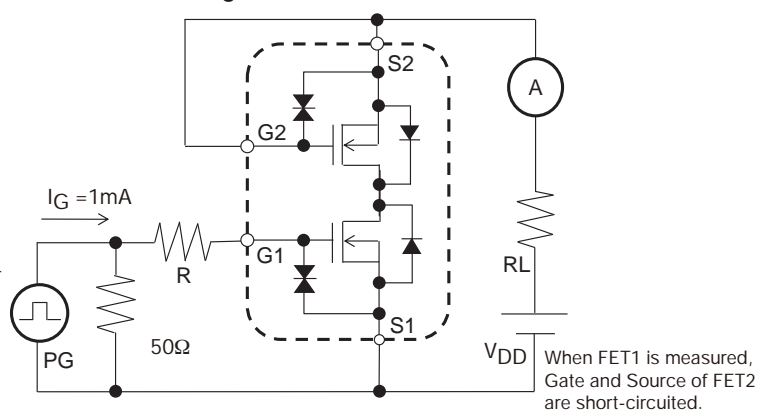
When FET1 is measured, +4.5V is added to V_{GS} of FET2.

Test Circuit 7
 $t_d(on)$, t_r , $t_d(off)$, t_f

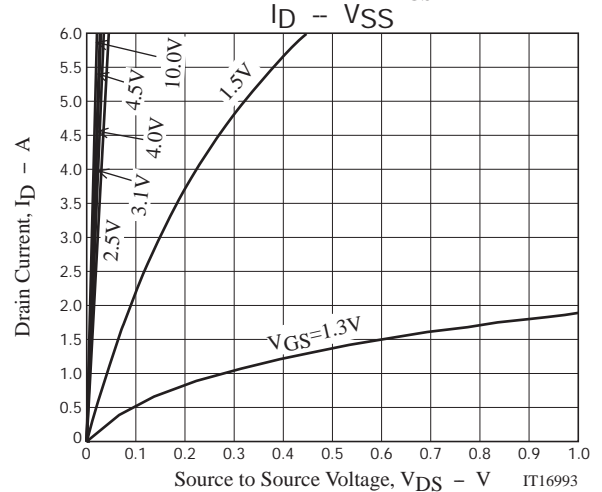
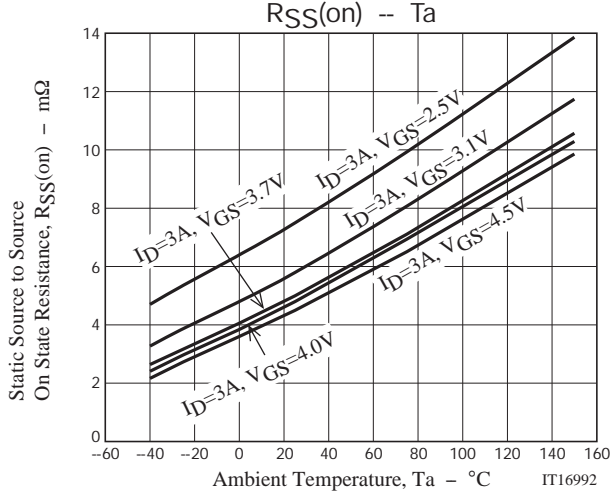
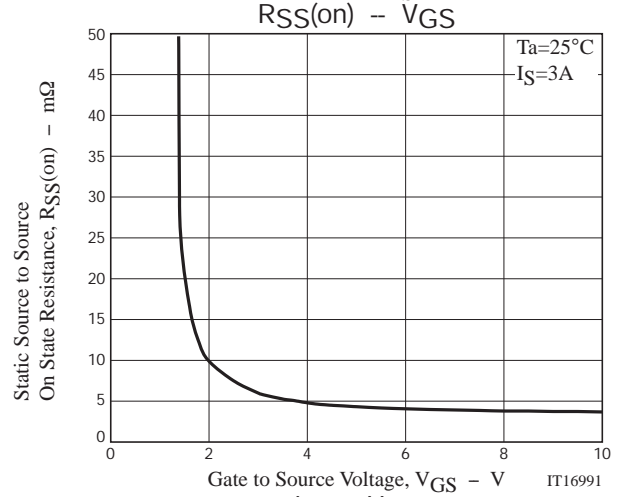
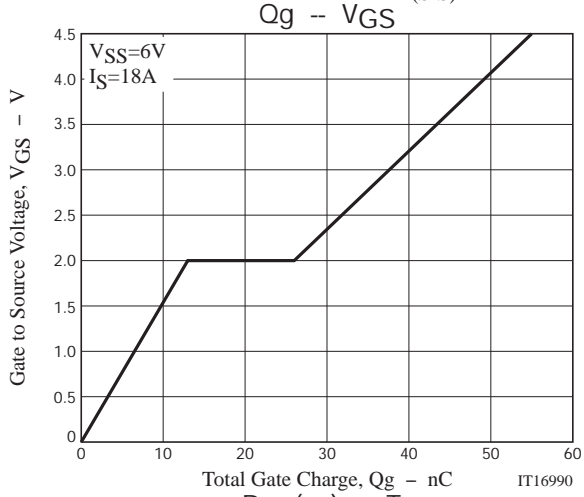
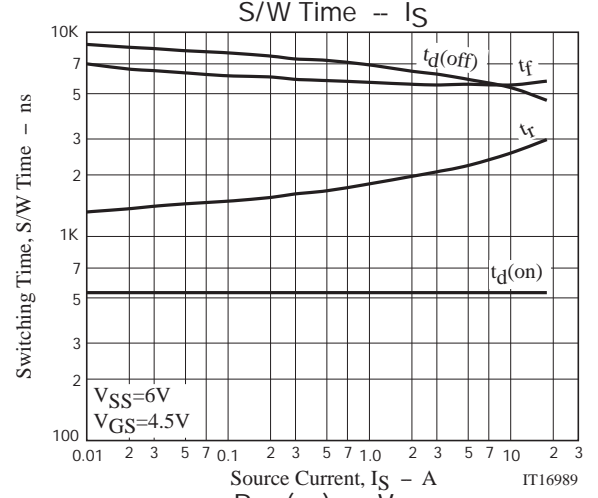
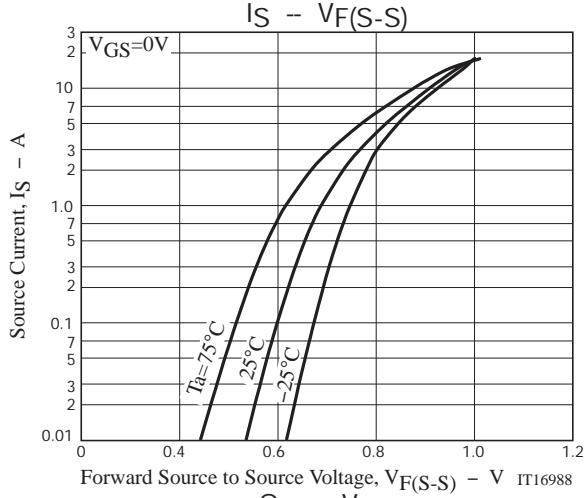
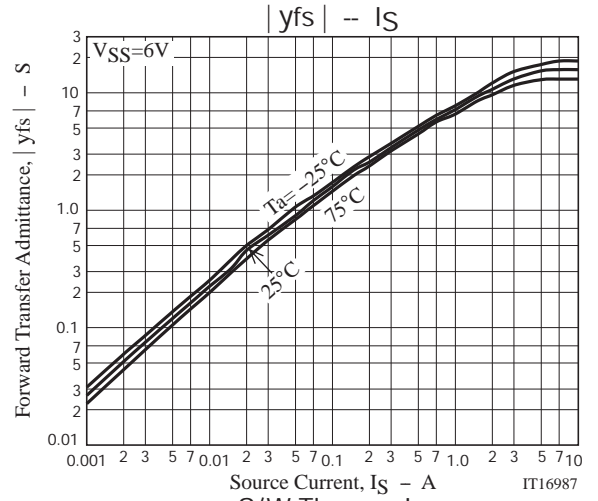
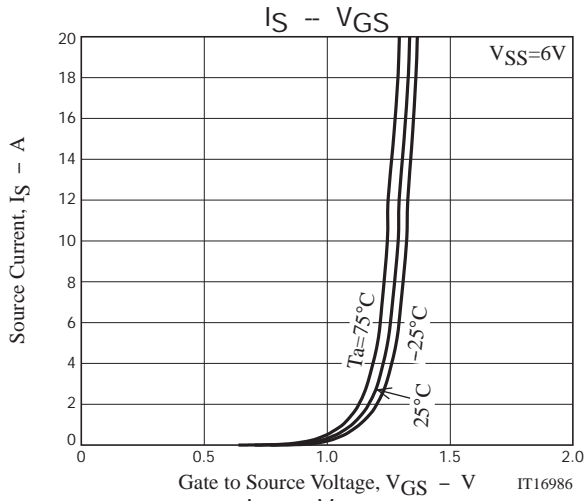


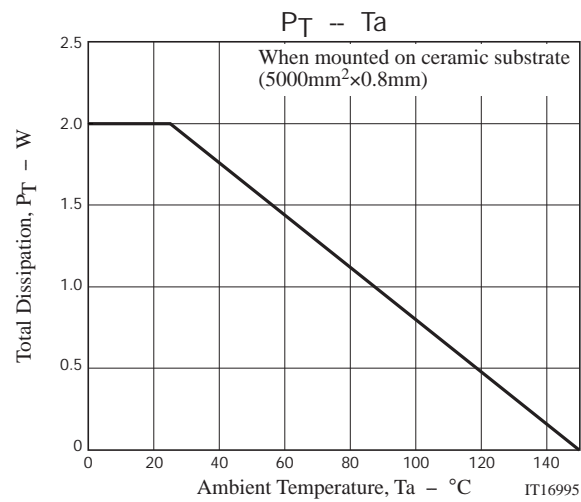
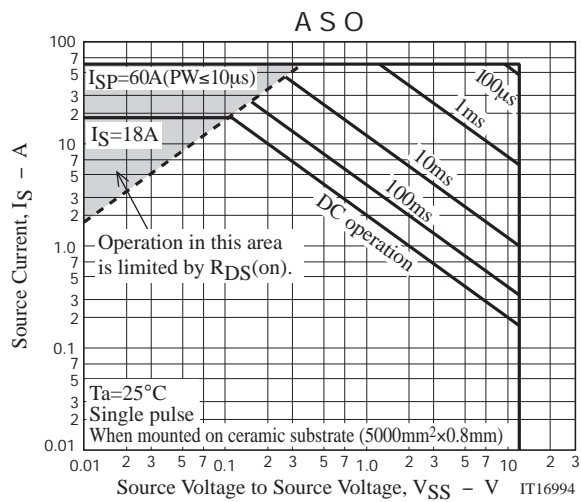
When FET1 is measured, Gate and Source of FET2 are short-circuited.

Test Circuit 8
 Q_g



When FET1 is measured, Gate and Source of FET2 are short-circuited.



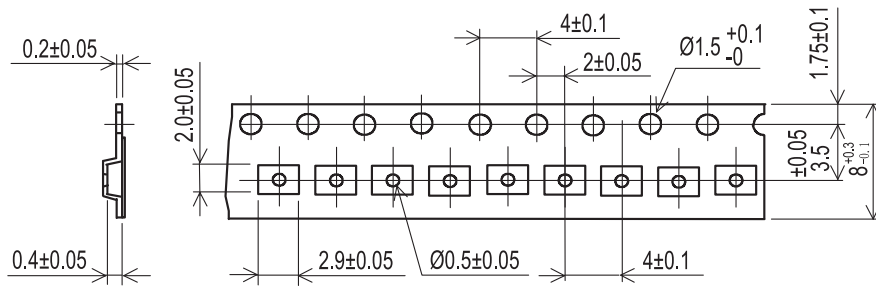


Taping Specification

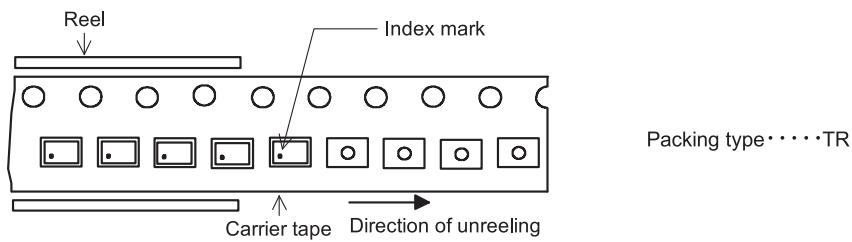
EFC6602R-TR

1. Taping Configuration

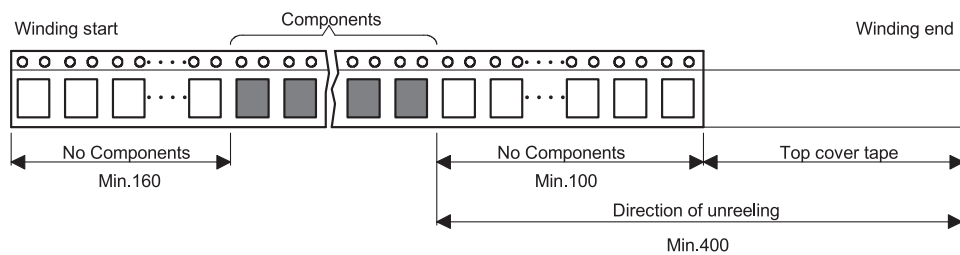
1-1 .Carrier Tape Size (unit:mm)



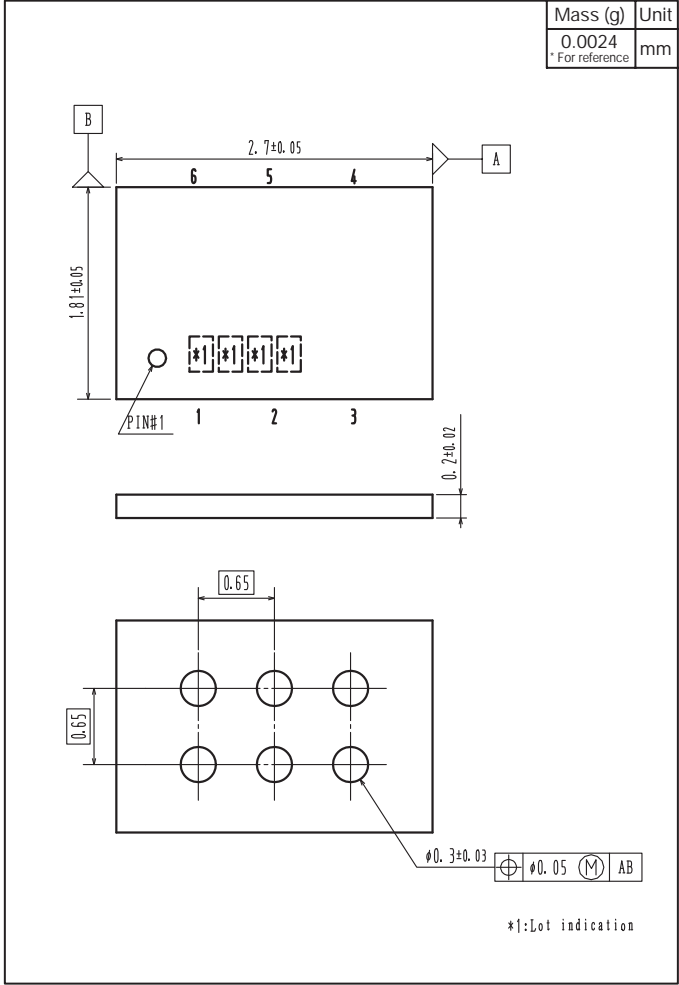
1-2 .Device Placement Direction



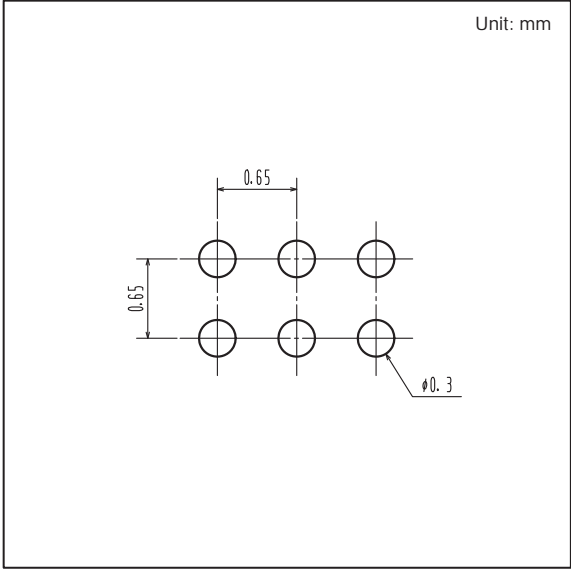
1-3 .Leader portion and Trailer portion (unit:mm)



Outline Drawing
EFC6602R-TR



Land Pattern Example



Note on usage : Since the EFC6602R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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